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APPLICATION NO.	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/729,865	12/05/2003	En-Hsing Chen	023-0029	8494
22120 7:	590 07/28/2006		EXAMINER	
ZAGORIN O'BRIEN GRAHAM LLP 7600B NORTH CAPITAL OF TEXAS HIGHWAY			NGUYEN, VAN THU T	
SUITE 350	I CAPITAL OF TEXAS H.	IGHWAY	ART UNIT	PAPER NUMBER
AUSTIN, TX	78731		2824	
			DATE MAILED: 07/28/200	6

Please find below and/or attached an Office communication concerning this application or proceeding.

Office Action Summary	10/729,865  Examiner  VanThu Nguyen	CHEN ET AL.  Art Unit	<del></del>
Office Action Summary		Art Unit	<del></del>
	VanThu Nguyen		
		2824	
The MAILING DATE of this communication a Period for Reply	ppears on the cover sheet with	h the correspondence address	
A SHORTENED STATUTORY PERIOD FOR REF WHICHEVER IS LONGER, FROM THE MAILING  - Extensions of time may be available under the provisions of 37 CFR after SIX (6) MONTHS from the mailing date of this communication.  - If NO period for reply is specified above, the maximum statutory perions for reply within the set or extended period for reply will, by state Any reply received by the Office later than three months after the mail earned patent term adjustment. See 37 CFR 1.704(b).	DATE OF THIS COMMUNIC 1.136(a). In no event, however, may a re- id will apply and will expire SIX (6) MONT ute, cause the application to become ABA	ATION.  bly be timely filed  HS from the mailing date of this communication  NDONED (35 U.S.C. § 133).	·
Status			
<ol> <li>Responsive to communication(s) filed on 12</li> <li>This action is FINAL.</li> <li>Since this application is in condition for allow closed in accordance with the practice under</li> </ol>	nis action is non-final. vance except for formal matte	• •	s is
Disposition of Claims			
4) ☐ Claim(s) 1-20,22,23 and 27-60 is/are pendin 4a) Of the above claim(s) 2-20,22,23,29-60 is 5) ☐ Claim(s) is/are allowed. 6) ☐ Claim(s) 1,27 and 28 is/are rejected. 7) ☐ Claim(s) is/are objected to. 8) ☐ Claim(s) are subject to restriction and	s/are withdrawn from conside	ration.	
Application Papers			
<ul> <li>9) The specification is objected to by the Examination The drawing(s) filed on 05 April 2004 is/are: Applicant may not request that any objection to the Replacement drawing sheet(s) including the correction. 11) The oath or declaration is objected to by the latent the correction of the correction of the latent the correction. </li> </ul>	a) accepted or b) object the drawing(s) be held in abeyand ection is required if the drawing(s	e. See 37 CFR 1.85(a). c) is objected to. See 37 CFR 1.12	• •
Priority under 35 U.S.C. § 119			
12) Acknowledgment is made of a claim for foreign a) All b) Some * c) None of:  1. Certified copies of the priority docume 2. Certified copies of the priority docume 3. Copies of the certified copies of the priority docume application from the International Bure * See the attached detailed Office action for a list	nts have been received. nts have been received in Ap iority documents have been r au (PCT Rule 17.2(a)).	plication No eceived in this National Stage	
Attachment(s)	Paper No(s)	mmary (PTO-413) Mail Date ormal Patent Application (PTO-152)	

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## Response to Amendment

1. Acknowledgement is made for Amendment filed on 06/12/2006.

1. Claim 1, 27-28 remain under examination.

2. Claims 21, 24-26 are cancelled in Amendment filed 06/12/06.

3. Claims 2-20, 22-23, 29-60 are withdrawn from consideration.

### Claim Rejections - 35 USC § 102

4. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

(b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.

5. Claim 1 is rejected under 35 U.S.C. 102(b) as being anticipated by U.S. Patent No. 6,380,636 (Tatsukawa).

Regarding claim 1, Tatsukawa discloses an integrated circuit comprising a memory array (memory cell array MA, see FIG. 7) including memory cells arranged in a plurality of series-connected NAND strings (see FIG. 8), said memory cells comprising modifiable conductance switch devices (floating gate memory cells MC11-MC22, which are programmed by tunneling current), said NAND strings including at a first end thereof a respective plurality of series selection devices of like type (select transistors DG1 and SGD1 connected to the first end of the NAND string on the left, select transistors SGS2 and DG4 connected to the first end of the NAND string on the right, see FIG. 8), wherein each NAND string includes a second plurality of series selection devices of like type at a second end thereof (select transistors SGS1 and DG2 connected to the second end of the NAND string on the left, select transistors DG3 and SGS2

connected to the second end of the NAND string on the right, also see FIG. 8), and wherein pairs of NAND strings are arranged so that (pair of NAND strings shown in FIG. 8):

a first group of control signals couples to the respective second end of one string of the pair to a global array line associated with the pair, and couples the respective first end of the other string of the pair to a respective bias node (control signals SS1 and SD2 connecting NAND string on the right to the main bit line MBL, and NAND string on the left to a program inhibit voltage); and

a second group of control signals couples the respective first end of said one string of the pair to a respective bias node, and couples the respective second end of the other string of the pair to the global array line associated with the pair (control signals SS2 and SD1 connecting NAND string on the left to the main bit line MBL, and NAND string on the right to a program inhibit voltage).

(See column 13, line 17 to column 14, line 18)

#### Claim Rejections - 35 USC § 103

- 6. The following is a quotation of 35 U.S.C. 103(a) which forms the basis for all obviousness rejections set forth in this Office action:
  - (a) A patent may not be obtained though the invention is not identically disclosed or described as set forth in section 102 of this title, if the differences between the subject matter sought to be patented and the prior art are such that the subject matter as a whole would have been obvious at the time the invention was made to a person having ordinary skill in the art to which said subject matter pertains. Patentability shall not be negatived by the manner in which the invention was made.
- 7. Claims 27-28 are rejected under 35 U.S.C. 103(a) as being unpatentable over Tatsukawa in view of U.S. Patent No. 6,411,548 (Sakui).

Tatsukawa discloses, as applied in prior rejection of claim 1, all claimed subject matter except further limitations as set forth in claims 27-28.

Regarding claim 27, Sakui also discloses series selection devices having a charge storage dielectric (select gate transistors S1(s) having block insulating films 40SSL between the control gate 27SSL and charge storing layer 26SSL, see FIG. 44).

Since Tatsukawa and Sakui are both from the same field of endeavor, the purpose disclosed by Sakui would have been recognized in the pertinent art of Tatsukawa.

It would have been obvious at the time the invention was made to a person having ordinary skill in the art to implement the structure of select gate transistors substantially the same as that of each memory cells for the purpose of reducing the area of the chip and the manufacturing cost (see column 39, line 55 to column 40, line 6).

Regarding claim 28, Sakui further discloses series selection devices are maintained by periodic programming biasing to a higher threshold voltage than fabricated (see FIGS. 52-53).

#### Response to Arguments

8. Applicant's arguments with respect to claims 1, 27-28 have been considered but are moot in view of the new ground(s) of rejection.

#### Conclusion

9. Applicant's amendment necessitated the new ground(s) of rejection presented in this Office action. Accordingly, **THIS ACTION IS MADE FINAL**. See MPEP § 706.07(a). Applicant is reminded of the extension of time policy as set forth in 37 CFR 1.136(a).

A shortened statutory period for reply to this final action is set to expire THREE MONTHS from the mailing date of this action. In the event a first reply is filed within TWO MONTHS of the mailing date of this final action and the advisory action is not mailed until after the end of the THREE-MONTH shortened statutory period, then the shortened statutory period

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will expire on the date the advisory action is mailed, and any extension fee pursuant to 37 CFR 1.136(a) will be calculated from the mailing date of the advisory action. In no event, however, will the statutory period for reply expire later than SIX MONTHS from the date of this final action.

10. Any inquiry concerning this communication or earlier communications from the examiner should be directed to VanThu Nguyen whose telephone number is (571) 272-1881. The examiner can normally be reached on Monday-Friday, 9:00am-5:30pm.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Richard Elms can be reached on (571) 272-1869. The fax phone number for the organization where this application or proceeding is assigned is 571-273-8300.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

July 17, 2006

VanThu Nguyen Primary Examiner

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